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WM8350

Wolfson AudioPlus™ Stereo CODEC with Power Management

DESCRIPTION

The WM8350 is an integrated audio and power management subsystem which provides a cost effective, single-chip solution for portable audio and multimedia systems.

The integrated audio CODEC provides all the necessary functions for high-quality stereo recording and playback. Programmable on-chip amplifiers allow for the direct connection of headphones and microphones with a minimum of external components. A programmable low-noise bias voltage is available to feed one or more electret microphones. Additional audio features include programmable high-pass filter in the ADC input path.

The WM8350 includes six programmable DC-DC converters, four low-dropout (LDO) regulators and a current limit switch to generate suitable supply voltages for each part of the system, including the integrated audio CODEC as well as off-chip components such as a digital core and I/O supplies, and LED lighting. An additional on-chip regulator maintains the backup power for always-on functions. The WM8350 can be powered by a lithium battery, by a wall adaptor or USB.

An on-chip battery charger supports both trickle charging and fast (constant current, constant voltage) charging of single-cell lithium batteries. The charge current, termination voltage, and charger time-out are programmable to suit different types of batteries.

Internal power management circuitry controls the start-up and shutdown sequencing of clocks and supply voltages. It also detects and handles conditions such as under-voltage, extreme temperatures, and deeply discharged or defective batteries, with a minimum of software involvement.

Two programmable constant-current sinks are available for driving LED strings, e.g. for display backlights or photo-flash applications, in a highly power-efficient way. Additional RGB LEDs can be driven through GPIO pins.

The WM8350 includes a 32.768kHz crystal oscillator, an internal RC oscillator, a real-time clock (RTC) and an alarm function capable of waking up the system. Internal circuitry can generate all clock signals required to start up the device.

The master clock for the audio CODEC can be input directly, or may be generated internally using an integrated, low power Frequency Locked Loop (FLL).

To extend battery life, fine-grained power management enables each function in the WM8350 to be independently powered down through the control interface. The WM8350 forms part of the Wolfson AudioPlus™ series of audio and power management solutions.

FEATURES

Stereo Hi-Fi CODEC

- DAC SNR 95dB ('A' weighted @ 48kHz), THD -81dB
- ADC SNR 95dB ('A' weighted @ 48kHz), THD -83dB
- 40mW on-chip headphone driver with 'capless' option
- 16Ω headphone load: THD -72dB, Po = 20mW
- 2 differential microphone inputs with low-noise bias voltage and programmable preamps
- Programmable high-pass filter for ADC
- Microphone and Headphone detection
- Auxiliary inputs for analogue signals
- Sample rates: 8, 11.025, 16, 22.05, 24, 32, 44.1 or 48kHz

System Control

- Support for 2-wire or 3/4-wire Control Interface
- Handles power sequencing, reset signals and fault conditions
- Autonomous power source selection (battery, wall adaptor or USB bus)
- Total current drawn from USB bus is limited to comply with USB 2.0 standard and USB OTG supplement

Supply Generation

- 2 x DC-DC Buck Converters (0.85V - 3.4V, Up to 1A)
- 2 x DC-DC Buck Converters (0.85V - 3.4V, Up to 500mA)
- 2 x DC-DC Boost Converters (5V - 20V, 40 to 200mA)
- 4 x LDO voltage regulators (0.9V - 3.3V, 150mA)

LED Drivers

- 2 programmable constant-current sinks, suitable for screen backlight or white LED photo flash
- 3 open-drain outputs for RGB LEDs

Battery Charger

- Single-cell Li-Ion / Li-Po battery charger
- Thermal protection for charge control; temperature monitoring available for thermal regulation
- LED outputs to indicate charge status and fault conditions

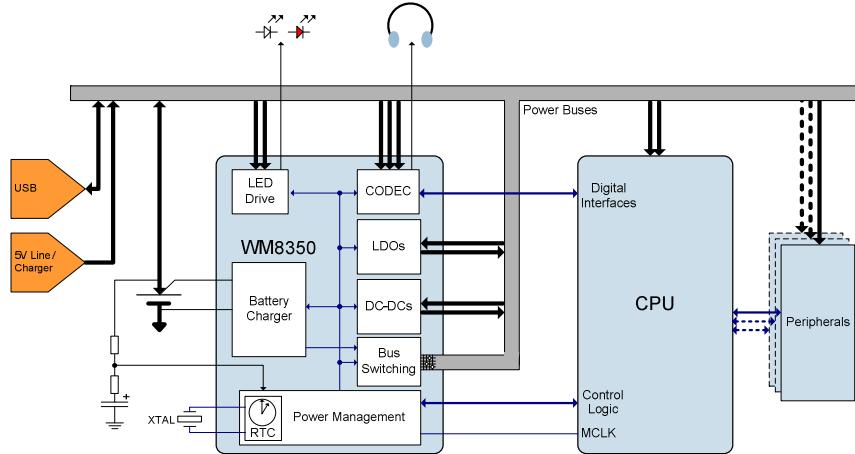
Additional Features

- "Always on" RTC with wake-up alarm
- Watchdog timer
- Up to 13 configurable GPIO pins
- On-chip crystal oscillator and internal RC oscillator
- Low power FLL supporting wide range of input clocks
- 7x7mm, 129 BGA package, 0.5mm ball pitch

APPLICATIONS

- Portable Audio and Media players
- Portable Navigation Devices
- Portable systems powered by single-cell lithium batteries

TYPICAL APPLICATIONS



The WM8350 is a complete audio and power management solution for portable media devices. The device incorporates four programmable step-down switching regulators, two step-up switching regulators, a full-featured battery charger, four Low Drop-Out (LDO) voltage regulators which can also serve as hot-swap outputs, a backup supply regulator, two programmable white LED drivers, a Real-Time Clock (RTC) alongside a 32.768kHz (32kHz) oscillator capable of operating from a backup battery, a 12-bit auxiliary ADC for precise measurements, a ROM-programmable power management state machine and numerous protection features all in a single 7x7mm BGA package. When only battery power is available, a battery switch provides power to all switching regulators (and some other internal modules). When external power is applied (eg. from USB or Wall adapter), the WM8350 seamlessly transitions from battery power (a single-cell Lithium battery) to the applicable external supply. The battery charger is then activated, all internal power for the device is drawn from the appropriate external power source and the battery is disconnected from the load. Maximum battery charge current and charge time are programmable. The USB power manager provides accurate current limiting for the USB pin under all conditions. The hot-swap outputs (LDOs in current-limited 'Switch Mode' operation) are ideal for powering memory cards and other devices that can be inserted while the system is fully powered.

The integrated Hi-Fi stereo CODEC incorporates preamps and a low-noise bias voltage for differential microphones, and flexible pseudo-differential drivers for headphone and differential/single-ended line outputs. External component requirements are reduced as no separate microphone or headphone amplifiers are required. Digital filter options are available in the ADC and DAC paths, to cater for application filtering. The WM8350 is capable of operating without any external clock, as it can derive all required clocks from its internal crystal oscillator, RC clock, and Frequency Locked Loop. An external low jitter clock may be required in some applications for high performance audio.

BLOCK DIAGRAM

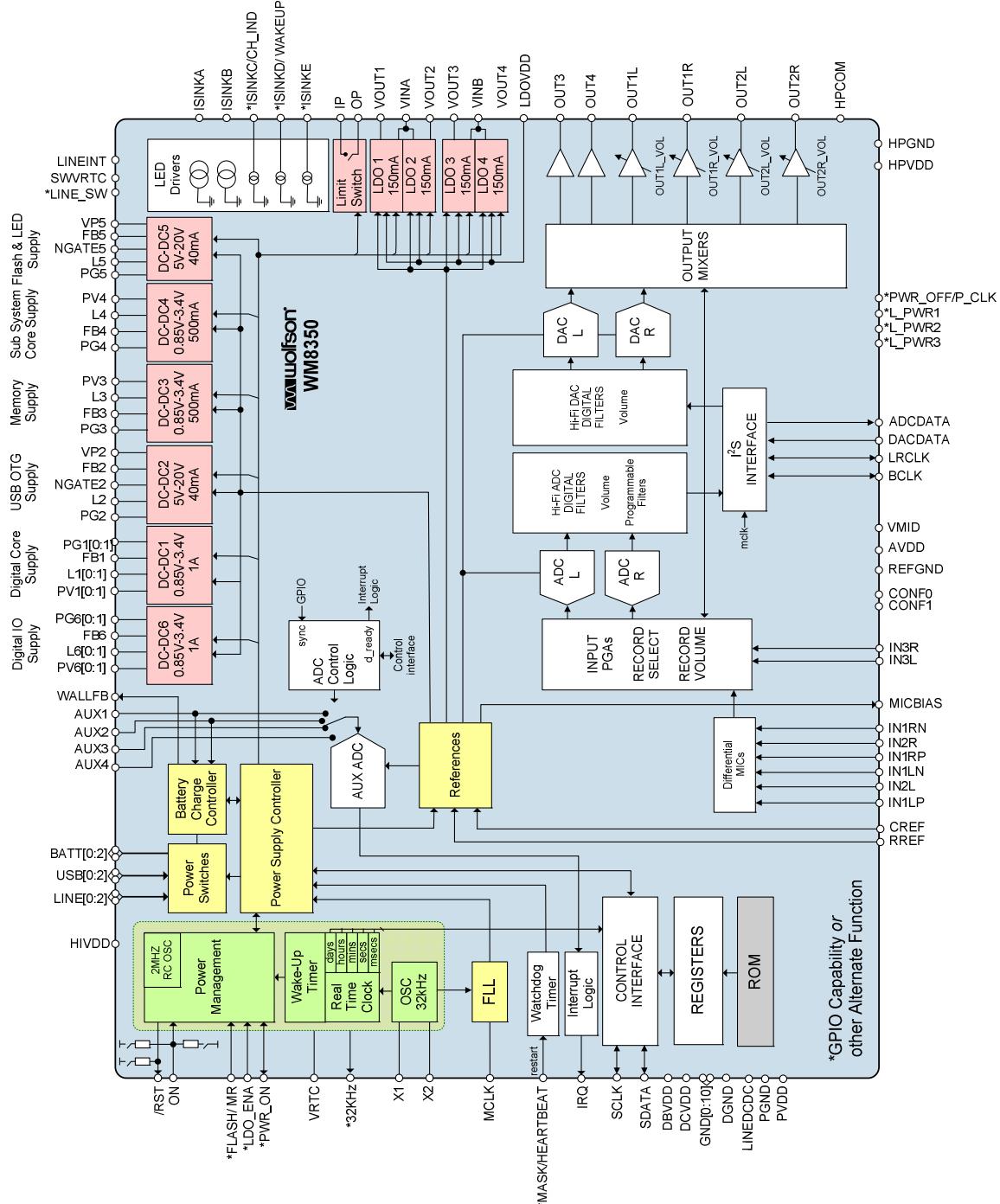


TABLE OF CONTENTS

DESCRIPTION	1
FEATURES.....	1
APPLICATIONS	1
TYPICAL APPLICATIONS	2
BLOCK DIAGRAM	3
TABLE OF CONTENTS	4
1 PIN CONFIGURATION	9
2 ORDERING INFORMATION.....	9
3 PIN DESCRIPTION.....	10
4 THERMAL CHARACTERISTICS	13
5 ABSOLUTE MAXIMUM RATINGS	14
6 RECOMMENDED OPERATING CONDITIONS.....	15
7 ELECTRICAL CHARACTERISTICS.....	16
7.1 HI-FI AUDIO CODEC.....	16
7.2 DC-DC STEP UP CONVERTER ELECTRICAL CHARACTERISTICS.....	18
7.3 DC-DC STEP DOWN CONVERTER ELECTRICAL CHARACTERISTICS	19
7.4 LDO REGULATOR ELECTRICAL CHARACTERISTICS	21
7.5 BATTERY CHARGER.....	22
7.6 CURRENT LIMIT SWITCH	22
7.7 LED DRIVERS	23
7.8 GENERAL PURPOSE INPUTS / OUTPUTS (GPIO)	23
7.9 DIGITAL INTERFACES	24
7.10 AUXILIARY ADC	24
8 TYPICAL POWER CONSUMPTION.....	25
9 TYPICAL PERFORMANCE DATA.....	27
9.1 AUDIO CODEC.....	27
9.2 DC-DC CONVERTERS.....	28
9.2.1 POWER EFFICIENCY	28
9.2.2 OUTPUT VOLTAGE REGULATION	29
9.2.3 DYNAMIC OUTPUT VOLTAGE	30
9.3 LDO REGULATORS	31
10 SIGNAL TIMING REQUIREMENTS.....	32
10.1 SYSTEM CLOCK TIMING	32
10.2 AUDIO INTERFACE TIMING - MASTER MODE	32
10.3 AUDIO INTERFACE TIMING - SLAVE MODE	33
10.4 AUDIO INTERFACE TIMING - TDM MODE	34
10.5 CONTROL INTERFACE TIMING.....	35
11 CONTROL INTERFACE	38
11.1 GENERAL DESCRIPTION	38
11.2 CONTROL INTERFACE MODES	38
11.3 2-WIRE SERIAL CONTROL MODE	39
11.4 3-WIRE SERIAL CONTROL MODE	42
11.5 4-WIRE SERIAL CONTROL MODE	43
11.6 REGISTER LOCKING	44
11.7 SPECIAL REGISTERS.....	44
11.7.1 CHIP ID	44
11.7.2 DEVICE INFORMATION.....	44

12 CLOCKING, TIMING AND SAMPLE RATES	45
12.1 GENERAL DESCRIPTION	45
12.1.1 CLOCKING THE AUDIO CODEC	46
12.1.2 CLOCKING THE DC-DC CONVERTERS	46
12.1.3 INTERNAL RC OSCILLATOR.....	46
12.2 CRYSTAL OSCILLATOR.....	46
12.3 CLOCKING AND SAMPLE RATES	47
12.3.1 SYSCLK CONTROL.....	49
12.3.2 ADC / DAC SAMPLE RATES.....	50
12.3.3 BCLK CONTROL	52
12.3.4 ADCLRCLK / DACLRCLK CONTROL	54
12.3.5 OPCLK CONTROL	55
12.3.6 SLOWCLK CONTROL	55
12.4 FLL	55
12.4.1 EXAMPLE FLL CALCULATION.....	58
12.4.2 EXAMPLE FLL SETTINGS	59
13 AUDIO CODEC SUBSYSTEM.....	60
13.1 GENERAL DESCRIPTION	60
13.2 AUDIO PATHS	61
13.3 ENABLING THE AUDIO CODEC	62
13.4 INPUT SIGNAL PATH	63
13.4.1 MICROPHONE INPUTS	63
13.4.2 ENABLING THE PRE-AMPLIFIERS	64
13.4.3 SELECTING INPUT SIGNALS.....	65
13.4.4 CONTROLLING THE PRE-AMPLIFIER GAINS.....	66
13.4.5 MICROPHONE BIASING	67
13.4.6 AUXILIARY INPUTS (IN3L AND IN3R).....	67
13.4.7 INPUT MIXERS.....	69
13.5 ANALOGUE TO DIGITAL CONVERTER (ADC).....	71
13.5.1 ADC VOLUME CONTROL	72
13.5.2 ADC HIGH-PASS FILTER.....	72
13.6 DIGITAL MIXING	73
13.6.1 DIGITAL SIDETONE	73
13.7 DIGITAL TO ANALOGUE CONVERTER (DAC).....	75
13.7.1 DAC PLAYBACK VOLUME CONTROL	76
13.7.2 DAC SOFT MUTE AND SOFT UN-MUTE.....	76
13.7.3 DAC DE-EMPHASIS	77
13.7.4 DAC OUTPUT PHASE AND MONO MIXING.....	78
13.7.5 DAC STOPBAND ATTENUATION.....	78
13.8 OUTPUT SIGNAL PATH	79
13.8.1 ENABLING THE ANALOGUE OUTPUTS	79
13.8.2 OUTPUT MIXERS.....	80
13.9 ANALOGUE OUTPUTS.....	83
13.9.1 OUT1L AND OUT1R.....	83
13.9.2 OUT2L AND OUT2R.....	85
13.9.3 HEADPHONE OUTPUTS EXTERNAL CONNECTIONS	87
13.9.4 OUT3 AND OUT4	89
13.10 DIGITAL AUDIO INTERFACE	91
13.10.1 AUDIO DATA FORMATS.....	91
13.10.2 AUDIO INTERFACE TDM MODE	94
13.10.3 TDM DATA FORMATS.....	94
13.10.4 LOOPBACK	96
13.11 COMPANDING	97
13.12 ADDITIONAL CODEC FUNCTIONS.....	99

13.12.1	HEADPHONE JACK DETECT	99
13.12.2	MICROPHONE DETECTION.....	100
13.12.3	MID-RAIL REFERENCE (VMID)	101
13.12.4	ANTI-POP CONTROL.....	102
13.12.5	UNUSED ANALOGUE INPUTS/OUTPUTS	103
13.12.6	ZERO CROSS TIMEOUT	105
13.12.7	INTERRUPTS AND FAULT PROTECTION	105
14	POWER MANAGEMENT SUBSYSTEM.....	106
14.1	GENERAL DESCRIPTION	106
14.2	POWER MANAGEMENT OPERATING STATES	106
14.2.1	HIBERNATE STATE SELECTION	107
14.3	POWER SEQUENCING AND CONTROL	108
14.3.1	STARTUP	108
14.3.2	POWER-UP SEQUENCING	109
14.3.3	SHUTDOWN.....	110
14.3.4	POWER CYCLING	111
14.3.5	REGISTER RESET	111
14.3.6	RESET SIGNALS.....	112
14.4	DEVELOPMENT MODE	114
14.4.1	CONTROL INTERFACE REDIRECTION	114
14.4.2	STARTING UP IN DEVELOPMENT MODE	115
14.4.3	CONFIGURING THE WM8350 IN DEVELOPMENT MODE	117
14.5	CUSTOM MODES	119
14.5.1	CONFIGURATION MODE 01	119
14.5.2	CONFIGURATION MODE 10	122
14.5.3	CONFIGURATION MODE 11	125
14.6	CONFIGURING THE DC-DC CONVERTERS	128
14.6.1	DC-DC CONVERTER ENABLE	128
14.6.2	CLOCKING	129
14.6.3	DC-DC BUCK (STEP-DOWN) CONVERTER CONTROL.....	129
14.6.4	DC-DC BOOST (STEP-UP) CONVERTER CONTROL.....	132
14.6.5	INTERRUPTS AND FAULT PROTECTION	134
14.7	CONFIGURING THE LDO REGULATORS	137
14.7.1	LDO REGULATOR ENABLE	137
14.7.2	LDO REGULATOR CONTROL	138
14.7.3	INTERRUPTS AND FAULT PROTECTION	140
14.7.4	ADDITIONAL CONTROL FOR LDO1	141
14.8	DC-DC CONVERTER OPERATION	142
14.8.1	OVERVIEW.....	142
14.8.2	DC-DC STEP DOWN CONVERTERS	143
14.8.3	DC-DC STEP UP CONVERTERS.....	144
14.9	LDO REGULATOR OPERATION	145
15	CURRENT LIMIT SWITCH	146
15.1	GENERAL DESCRIPTION	146
15.2	CONFIGURING THE CURRENT LIMIT SWITCH.....	146
15.2.1	CURRENT LIMIT SWITCH ENABLE	146
15.2.2	CURRENT LIMIT SWITCH BULK DETECTION CONTROL	147
15.2.3	INTERRUPTS AND FAULT PROTECTION	147
16	CURRENT SINKS (LED DRIVERS)	149
16.1	GENERAL DESCRIPTION	149
16.2	CONSTANT-CURRENT SINKS.....	149
16.2.1	ENABLING THE SINK CURRENT	149
16.2.2	PROGRAMMING THE SINK CURRENT.....	150
16.2.3	FLASH MODE.....	150
16.2.4	ON/OFF RAMP TIMING	152

16.2.5	INTERRUPTS AND FAULT PROTECTION	152
16.3	OPEN-DRAIN LED OUTPUTS	153
16.4	LED DRIVER CONNECTIONS	153
17	POWER SUPPLY CONTROL.....	154
17.1	GENERAL DESCRIPTION	154
17.2	BATTERY POWERED OPERATION.....	155
17.3	WALL ADAPTOR (LINE) POWERED OPERATION	155
17.4	USB POWERED OPERATION.....	156
17.5	EXTERNAL INTERRUPTS	158
17.6	BACKUP POWER	158
17.7	BATTERY CHARGER	159
17.7.1	GENERAL DESCRIPTION.....	159
17.7.2	BATTERY CHARGER ENABLE.....	160
17.7.3	TRICKLE CHARGING.....	161
17.7.4	FAST CHARGING.....	163
17.7.5	BATTERY CHARGER TIMEOUT AND TERMINATION	165
17.7.6	BATTERY CHARGER STATUS	166
17.7.7	BATTERY FAULT CONDITIONS	167
17.7.8	INTERRUPTS AND FAULT PROTECTION	169
18	SYSTEM MONITORING AND UNDERVOLTAGE LOCKOUT (UVLO)	170
19	AUXILIARY ADC.....	172
19.1	GENERAL DESCRIPTION	172
19.2	INITIATING AUXADC MEASUREMENTS	173
19.3	VOLTAGE SCALING AND REFERENCES.....	175
19.4	AUXADC READBACK	176
19.5	CALIBRATION.....	178
19.6	DIGITAL COMPARATORS.....	179
19.7	AUXADC INTERRUPTS	180
20	GENERAL PURPOSE INPUTS / OUTPUTS (GPIO).....	181
20.1	GENERAL DESCRIPTION	181
20.1.1	CONFIGURING GPIO PINS	182
20.1.2	INPUT DE-BOUNCE	183
20.1.3	GPIO INTERRUPTS	183
20.2	GPIO ALTERNATE FUNCTIONS	184
20.2.1	LIST OF ALTERNATE FUNCTIONS	184
20.2.2	SELECTING GPIO ALTERNATE FUNCTIONS	187
21	VOLTAGE REFERENCES.....	191
21.1	MAIN REFERENCE (VREF)	191
21.2	LOW-POWER REFERENCE	191
22	REAL-TIME CLOCK (RTC).....	192
22.1	GENERAL DESCRIPTION	192
22.2	RTC CONTROL.....	192
22.2.1	MODES OF OPERATION	192
22.2.2	RTC TIME REGISTERS	192
22.2.3	SETTING THE TIME	193
22.2.4	RTC ALARM REGISTERS	193
22.2.5	SETTING THE ALARM	195
22.3	TRIMMING THE RTC	195
22.4	RTC GPIO OUTPUT.....	197
22.5	RTC INTERRUPTS	198
23	WATCHDOG TIMER.....	199
24	INTERRUPT CONTROLLER.....	201
24.1	CONFIGURING THE IRQ PIN	201

24.2	FIRST-LEVEL INTERRUPTS	202
24.3	SECOND-LEVEL INTERRUPTS	203
24.3.1	OVERCURRENT INTERRUPT	203
24.3.2	UNDERVOLTAGE INTERRUPTS	203
24.3.3	CURRENT SINK (LED DRIVER) INTERRUPTS	204
24.3.4	EXTERNAL INTERRUPTS	205
24.3.5	CODEC INTERRUPTS	205
24.3.6	GPIO INTERRUPTS	206
24.3.7	AUXADC AND DIGITAL COMPARATOR INTERRUPTS	207
24.3.8	RTC INTERRUPTS	207
24.3.9	SYSTEM INTERRUPTS	208
24.3.10	CHARGER INTERRUPTS	208
24.3.11	USB INTERRUPTS	209
24.3.12	WAKE-UP INTERRUPTS	210
25	TEMPERATURE SENSING	211
25.1	CHIP TEMPERATURE MONITORING	211
26	REGISTER MAP	212
26.1	OVERVIEW	212
27	REGISTER BITS BY ADDRESS	223
28	DIGITAL FILTER CHARACTERISTICS	328
28.1	DAC FILTER RESPONSES	328
28.2	ADC FILTER RESPONSES	329
29	APPLICATIONS INFORMATION	330
29.1	TYPICAL CONNECTIONS	330
29.2	VOLTAGE REFERENCE (VREF) COMPONENTS	331
29.3	DC-DC (STEP-DOWN) CONVERTER EXTERNAL COMPONENTS	331
29.4	DC-DC (STEP-UP) CONVERTER EXTERNAL COMPONENTS	333
29.4.1	DC-DC (STEP-UP) CONVERTERS - CONSTANT VOLTAGE MODE	333
29.4.2	DC-DC (STEP-UP) CONVERTERS - CONSTANT CURRENT MODE	335
29.4.3	DC-DC (STEP-UP) CONVERTERS - USB MODE	336
29.4.4	DC-DC (STEP-UP) CONVERTERS RECOMMENDED COMPONENTS	336
29.5	LDO REGULATOR EXTERNAL COMPONENTS	337
29.6	PCB LAYOUT	338
30	PACKAGE DIAGRAM	339
31	IMPORTANT NOTICE	340

1 PIN CONFIGURATION

	1	2	3	4	5	6	7	8	9	10	11	12	13
A	VP5	PG5	OP	PV1	L1	PG1	PG6	L6	PV6	FB6	GPIO12	FB2	PG2
B	L5	NGATE5	IP	PV1	L1	PG1	PG6	L6	PV6	PVDD	GPIO10	NGATE2	VP2
C	L4	PG4	FB4	FB5	LINEDCD C	FB1	GND	GND	AUX4	GPIO11	PGND	PG3	L2
D	PV4	BATT	HIVDD	N/A	N/A	N/A	N/A	N/A	N/A	N/A	FB3	PV3	L3
E	BATT	BATT	WALLFB	N/A	N/A	N/A	N/A	N/A	N/A	N/A	ISINKA	ISINKB	SINKGND
F	LINE	LINE	LINE	N/A	N/A	GND	GND	GND	N/A	N/A	VOUT4	LDOVDD	VINB
G	USB	USB	USB	N/A	N/A	GND	GND	GND	N/A	N/A	VOUT2	VOUT3	VINA
H	VRTC	LINEINT	CREF	N/A	N/A	GND	GND	GND	N/A	N/A	AUX1	VOUT1	AUX3
J	CONF0	X1	RREF	N/A	N/A	N/A	N/A	N/A	N/A	N/A	OUT1R	HPCOM	AUX2
K	CONF1	ON	X2	N/A	N/A	N/A	N/A	N/A	N/A	N/A	OUT1L	OUT4	HPVDD
L	GPIO0	/RST	SWVRTC	IRQ	GPIO5	GPIO8	GPIO9	BCLK	LRCLK	IN3L	IN1LN	OUT3	HPGND
M	GPIO2	GPIO1	SDA	GPIO6	DGND	MCLK	ADCDATA	AVDD	IN3R	INL2	MICBIAS	OUT2R	OUT2L
N	GPIO3	SCL	GPIO4	GPIO7	DCVDD	DBVDD	DACDATA	REFGND	VMID	IN1LP	INR2	IN1RP	IN1RN

7mm x 7mm BGA .Z

Notes: Pin names beginning with a lower-case "n" indicate that the pin is active low.
Colour coding indicates function of pins in typical usage:

- DC-DC converters
- LDO voltage regulators
- Power management functions
- Analogue pins for audio codec
- Digital pins for audio codec
- Quiet ground
- Others

2 ORDERING INFORMATION

ORDER CODE	TEMPERATURE RANGE	PACKAGE	MOISTURE SENSITIVITY LEVEL	PEAK SOLDERING TEMPERATURE
WM8350GEB/V	-25°C to +85°C	129-ball BGA (7 x 7 mm) (Pb-free)	MSL3	260°C
WM8350GEB/RV	-25°C to +85°C	129-ball BGA (7 x 7 mm) (Pb-free, tape and reel)	MSL3	260°C

Note:

Reel quantity = 2,200

3 PIN DESCRIPTION

Notes:

Pins are listed in alphabetical order by name.

NAME	LOCATION(S)	TYPE	POWER DOMAIN	DESCRIPTION
ADCDATA	M7	Digital Output	DBVDD	Digital audio output (typically from on-chip audio ADC to external IC)
AUX1	H11	Analogue Input	LINE	Auxiliary ADC input AUX1 (Special function for connection to temperature-sensing NTC resistor in battery pack)
AUX2	J13	Analogue Input	LINE	Auxiliary ADC input AUX2
AUX3	H13	Analogue Input	LINE	Auxiliary ADC input AUX3
AUX4	C9	Analogue Input	LINE	Auxiliary ADC input AUX4
AVDD	M8	Supply		Analogue supply for audio CODEC
BATT	E1, E2, D2	Analogue I/O		Main battery power connection (can draw power or charge battery)
BCLK	L8	Digital I/O	DBVDD	Bit clock signal for digital audio interface
CREF	H3	Analogue Output	VRRTC	Decoupling for VREF reference voltage (connect capacitor here)
CONF0	J1	Digital Input	VRRTC	Start-up configuration pin 0
CONF1	K1	Digital Input	VRRTC	Start-up configuration pin 1
DACDATA	N7	Digital Input	DBVDD	Digital audio input (typically from external IC to on-chip audio DAC)
DCVDD	N5	Supply		Digital core supply; powers digital core of audio CODEC
DBVDD	N6	Supply		Digital I/O buffer supply; powers digital audio interface, control interface and pins GPIO4 to GPIO9
DGND	M5	Supply		Digital ground; return path for DCVDD and DBVDD supplies
FB1	C6	Analogue Input	PV1	DC-DC1 feedback pin
FB2	A12	Analogue Input	VP2	DC-DC2 feedback pin
FB3	D11	Analogue Input	PV3	DC-DC3 feedback pin
FB4	C3	Analogue Input	PV4	DC-DC4 feedback pin
FB5	C4	Analogue Input	VP5	DC-DC5 feedback pin
FB6	A10	Analogue Input	PV6	DC-DC6 feedback pin
GND	F6, F7, F8, G6,G7, G8, H6, H7, H8, C7, C8	Supply		Quiet ground connection for audio CODEC. Note that DC-DC Converters use a separate ground connection.
GPIO0	L1	Digital I/O	VRRTC	General Purpose Input/Output pin 0
GPIO1	M2	Digital I/O	VRRTC	General Purpose Input/Output pin 1
GPIO2	M1	Digital I/O	VRRTC	General Purpose Input/Output pin 2
GPIO3	N1	Digital I/O	VRRTC	General Purpose Input/Output pin 3
GPIO4	N3	Digital I/O	DBVDD	General Purpose Input/Output pin 4
GPIO5	L5	Digital I/O	DBVDD	General Purpose Input/Output pin 5
GPIO6	M4	Digital I/O	DBVDD	General Purpose Input/Output pin 6
GPIO7	N4	Digital I/O	DBVDD	General Purpose Input/Output pin 7
GPIO8	L6	Digital I/O	DBVDD	General Purpose Input/Output pin 8
GPIO9	L7	Digital I/O	DBVDD	General Purpose Input/Output pin 9
GPIO10	B11	Digital I/O	LINE	General Purpose Input/Output pin 10
GPIO11	C10	Digital I/O	LINE	General Purpose Input/Output pin 11
GPIO12	A11	Digital I/O	LINE	General Purpose Input/ Output pin 12
HIVDD	D3	Analogue Output		Analogue output from power management unit which determines highest supply from Line, Battery or USB.
HPCOM	J12	Analogue Input	HPVDD	Headphone output amplifier noise compensation input
HPGND	L13	Supply	HPVDD	Headphone ground; return path for HPVDD supply

NAME	LOCATION(S)	TYPE	POWER DOMAIN	DESCRIPTION
HPVDD	K13	Supply		Headphone supply – powers the analogue outputs OUT1L, OUT1R, OUT2L, OUT2R, OUT3 and OUT4
IN1LN	L11	Analogue Input	AVDD	Inverting input for left microphone channel
IN1LP	N10	Analogue Input	AVDD	Non-inverting input 1 for left microphone channel
IN1RN	N13	Analogue Input	AVDD	Inverting input for right microphone channel
IN1RP	N12	Analogue Input	AVDD	Non-inverting input 1 for right microphone channel
IN2L	M10	Analogue Input	AVDD	Non-inverting input 2 for left microphone channel
IN2R	N11	Analogue Input	AVDD	Non-inverting input 2 for right microphone channel
IN3L	L10	Analogue Input	AVDD	Auxiliary input for analogue audio signals (left channel)
IN3R	M9	Analogue Input	AVDD	Auxiliary input for analogue audio signals (right channel)
IP	B3	Analogue Input		Power input to current limit switch
ISINKA	E11	Analogue Output	LDOVDD	Constant-current LED driver A
ISINKB	E12	Analogue Output	LDOVDD	Constant-current LED driver B
L1	A5, B5	Analogue I/O	PV1	DC-DC1 inductor connection
L2	C13	Analogue I/O	VP2	DC-DC2 inductor connection
L3	D13	Analogue I/O	PV3	DC-DC3 inductor connection
L4	C1	Analogue I/O	PV4	DC-DC4 inductor connection
L5	B1	Analogue I/O	VP5	DC-DC5 inductor connection
L6	A8, B8	Analogue I/O	PV6	DC-DC6 inductor connection
LDOVDD	F12	Supply		LDO amplifier supply voltage
LINEDCDC	C5	Supply		Supply connection for DC-DC 1, 4 and 5 control circuits
LINEINT	H2	Supply		Supply connection for Internal Reference circuits
LINE	F1, F2, F3	Supply		LINE supply connection
LRCLK	L9	Digital I/O	DBVDD	Word clock (left/right clock) signal for digital audio interface
MCLK	M6	Digital I/O	DBVDD	Master Clock (may be generated internally or externally)
MICBIAS	M11	Analogue Output	AVDD	Low-noise bias voltage for condenser microphones (connect decoupling capacitor here)
NGATE2	B12	Analogue Output	VP2	DC-DC2 connection to gate of external power FET
NGATE5	B2	Analogue Output	VP5	DC-DC5 connection to gate of external power FET
IRQ	L4	Digital Output open-drain	DBVDD	Interrupt signal from WM8350 to host processor
ON	K2	Digital Input	VRTC	Connection for power-on switch
/RST	L2	Digital Output open-drain	DBVDD	System Reset Signal (active low)
OP	A3	Analogue Output		Power output from current limit switch
OUT1L	K11	Analogue Output	AVDD	Left channel analogue audio output 1
OUT2L	M13	Analogue Output	AVDD	Left channel analogue audio output 2
OUT1R	J11	Analogue Output	AVDD	Right channel analogue audio output 1
OUT2R	M12	Analogue Output	AVDD	Right channel analogue audio output 2
OUT3	L12	Analogue Output	AVDD	Analogue audio output 3 (or pseudo-ground output for capacitor-less headphone outputs)
OUT4	K12	Analogue Output	AVDD	Analogue audio output 4
PG1	A6, B6	Supply		DC-DC1 power ground
PG2	A13	Supply		DC-DC2 power ground
PG3	C12	Supply		DC-DC3 power ground
PG4	C2	Supply		DC-DC4 power ground
PG5	A2	Supply		DC-DC5 power ground
PG6	A7, B7	Supply		DC-DC6 power ground
PGND	C11	Supply		Ground connection
PV1	A4, B4,	Supply		DC-DC1 line or battery power input
PV3	D12	Supply		DC-DC3 line or battery power input
PV4	D1	Supply		DC-DC4 line or battery power input

WM8350

Production Data

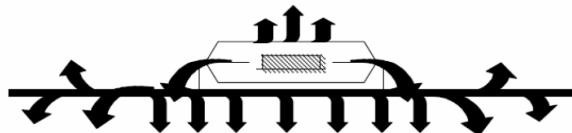
NAME	LOCATION(S)	TYPE	POWER DOMAIN	DESCRIPTION
PV6	A9, B9	Supply		DC-DC6 power input
PVDD	B10	Supply		Supply connection for DC-DC 2, 3 and 6 control circuits
REFGND	N8	Supply		Reference ground for audio ADC and DAC
RREF	J3	Analogue Output		Connection for external 100kΩ current reference resistor
SCLK	N2	Digital Input	DBVDD	Clock signal for 2-wire serial control interface (5V Tolerant)
SDATA	M3	Digital I/O	DBVDD	Data line for 2-wire serial control interface (5V Tolerant)
SINKGND	E13	Supply		Ground connection for ISINKA and ISINKB
SWVRTC	L3	Analogue Output	VRTC	Switchable VRTC output. Typically used for battery temperature monitoring
USB	G1, G2, G3	Supply		Connection to USB power rail
VINA	G13	Supply		Input to voltage regulators LDO1 and LDO2
VINB	F13	Supply		Input to voltage regulators LDO3 and LDO4
VMID	N9	Analogue I/O	AVDD	Reference voltage (normally AVDD/2) for audio CODEC (connect capacitor here)
VOUT1	H12	Analogue Output	VINA	Output of voltage regulator LDO1
VOUT2	G11	Analogue Output	VINA	Output of voltage regulator LDO2
VOUT3	G12	Analogue Output	VINB	Output of voltage regulator LDO3
VOUT4	F11	Analogue Output	VINB	Output of voltage regulator LDO4
VP2	B13	Supply		DC-DC2 power input
VP5	A1	Supply		DC-DC5 power input
VRTC	H1	Supply		Backup power connection (WM8350 can draw power from this pin or re-charge the backup power source)
WALLFB	E3	Analogue Input	LINE	Connection to Wall feedback
X1	J2	Analogue Input	VRTC	Connection for 32.768kHz crystal (input to oscillator from crystal) or 32.768kHz external clock input (when not using crystal)
X2	K3	Analogue Output	VRTC	Connection for 32.768kHz crystal (output from oscillator to crystal)

4 THERMAL CHARACTERISTICS

Thermal analysis must be performed in the intended application to prevent the WM8350 from exceeding maximum junction temperature. Several contributing factors affect thermal performance most notably the physical properties of the mechanical enclosure, location of the device on the PCB in relation to surrounding components and the number of PCB layers. Connecting the nine central GND balls through thermal vias and into a large ground plane will aid heat extraction.

Three main heat transfer paths exist to surrounding air:

- Package top to air (radiation).
- Package bottom to PCB (radiation).
- Package leads to PCB (conduction).



The temperature rise T_R is given by $T_R = P_D * \Theta_{JA}$

- P_D is the power dissipated by the device.
- Θ_{JA} is the thermal resistance from the junction of the die to the ambient temperature and is therefore a measure of heat transfer from the die to surrounding air.
- For WM8350, $\Theta_{JA} = 32^\circ\text{C}/\text{W}$

The junction temperature T_J is given by $T_J = T_A + T_R$

- T_A , is the ambient temperature.

The worst case conditions are when the WM8350 is operating in a high ambient temperature, with low supply voltage, high duty cycle and high output current. Under such conditions, it is possible that the heat dissipated could exceed the maximum junction temperature of the device. Care must be taken to avoid this situation. An example calculation of the junction temperature is given below.

- $P_D = 1\text{W}$ (example figure)
- $\Theta_{JA} = 32^\circ\text{C}/\text{W}$
- $T_R = P_D * \Theta_{JA} = 32^\circ\text{C}$
- $T_A = 85^\circ\text{C}$ (example figure)
- $T_J = T_A + T_R = 117^\circ\text{C}$

The minimum and maximum operating junction temperatures for the WM8350 are quoted in Section 5. The maximum junction temperature is 125°C . Therefore, the junction temperature in the above example is within the operating limits of the WM8350.

5 ABSOLUTE MAXIMUM RATINGS

Absolute Maximum Ratings are stress ratings only. Permanent damage to the device may be caused by continuously operating at or beyond these limits. Device functional operating limits and guaranteed performance specifications are given under Electrical Characteristics at the test conditions specified.



ESD Sensitive Device. This device is manufactured on a CMOS process. It is therefore generically susceptible to damage from excessive static voltages. Proper ESD precautions must be taken during handling and storage of this device.

Wolfson tests its package types according to IPC/JEDEC J-STD-020B for Moisture Sensitivity to determine acceptable storage conditions prior to surface mount assembly. These levels are:

MSL1 = unlimited floor life at <30°C / 85% Relative Humidity. Not normally stored in moisture barrier bag.

MSL2 = out of bag storage for 1 year at <30°C / 60% Relative Humidity. Supplied in moisture barrier bag.

MSL3 = out of bag storage for 168 hours at <30°C / 60% Relative Humidity. Supplied in moisture barrier bag.

The WM8350 has been classified as MSL3.

CONDITION	MIN	MAX
BATT, LINE and USB voltage	-0.3V	+7V
Input voltage for LDO regulators (pins VINA, VINB)	-0.3V	+7V
Analogue supply voltages (AVDD, HPVDD)	-0.3V	+4.5V
Digital supply voltages (DCVDD, DBVDD)	-0.3V	+4.5V
Voltage range for CODEC analogue inputs	-0.3V	AVDD + 0.3V
Voltage range for digital inputs	-0.3V	DBVDD + 0.3V
Master Clock Frequency (When MCLK_DIV set to divide by 2)		37MHz
Operating Temperature Range, T _A	-25°C	+85°C
Junction Temperature, T _J	-20°C	+125°C
Thermal Impedance Junction to Ambient, θ _{JA}		32°C/W
Storage temperature prior to soldering	30°C max / 60% RH max	
Storage temperature after soldering	-65°C	+150°C
Soldering temperature (10 seconds)		+260°C
Note: These ratings assume that all ground pins are at 0V.		

6 RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS
Digital Supply Range (Core)	DCVDD	1.71		3.6	V
Digital Supply Range (Buffer)	DBVDD	1.71		3.6	V
Headphone Supply Range	HPVDD	2.5		3.6	V
Analogue Supply Range	AVDD	2.5		3.6	V
Line Input Source	LINE	2.95		5.5	V
Battery Input Source	BATT	2.95		4.2	V
USB Input Source	USB	4.75		5.25	V
LDO Input Source	VINA, VINB	0		5.5	V
Ground	GND, PGND, DGND, HPGND, REFGND, PG1, PG2, PG3, PG4, PG5, PG6		0		V

7 ELECTRICAL CHARACTERISTICS

7.1 HI-FI AUDIO CODEC

Test Conditions

DCVDD = 1.8V, AVDD = HPVDD = 3.3V, TA = +25°C, 1kHz signal, fs = 48kHz, 24-bit audio data unless otherwise stated.

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Microphone Preamp Inputs (IN1LP, IN1LN, IN1RP, IN1RN)						
Full-scale Input Signal Level (0dB) – note this changes with AVDD	V _{INFS}			1 0		V rms dBV
Mic preamp equivalent input noise	At 35.25dB gain			150		µV
Input resistance	R _{MICIN}	Gain set to 35.25dB		2.3		kΩ
Input resistance	R _{MICIN}	Gain set to 0dB		64		kΩ
Input resistance	R _{MICIN}	Gain set to -12dB		101		kΩ
Input Capacitance	C _{MICIN}			2		pF
Recommended decoupling cap	C _{DECOP}			0.33		µF
MIC Programmable Gain Amplifier (PGA)						
Programmable Gain			-12		35.25	dB
Programmable Gain Step Size		Monotonic		0.75		dB
Mute Attenuation				-90		dB
Selectable Input Gain Boost (0/+20dB)						
Gain Boost			0		20	dB
Auxiliary Analogue Inputs (IN3L, IN3R)						
Full-scale Input Signal Level (0dB) – note this changes with AVDD	V _{INFS}			1.0 0		V rms dBV
PGA gain range to summer			-12		+6	dB
PGA step size to summer				3		dB
Input Resistance	R _{AUXIN}			32		kΩ
Input Capacitance	C _{AUXIN}			10		pF
Analogue to Digital Converter (ADC)						
Signal to Noise Ratio (Note 1, 2)		A-weighted, 0dB gain	86	95		dB
Total Harmonic Distortion (Note 4)		-2dBV Input	-75	-83		dB
Digital to Analogue Converter (DAC) to Line-Out (OUT1L, OUT1R with 10kΩ / 50pF load)						
Full-scale output		PGA gains set to 0dB		HPVDD/3.3		V rms
Signal to Noise Ratio (Note 1, 2)	SNR	A-weighted	90	95		dB
Total Harmonic Distortion (Note 3)	THD+N	R _L = 10kΩ full-scale signal	-75	-81		dB
Channel Separation (Note 4)		1kHz signal		89		dB
Output Mixers						
PGA gain range into mixer			-15	0	+6	dB
PGA gain step into mixer				3		dB
Analogue Output PGAs (OUT1L, OUT1R, OUT2L, OUT2R)						
Programmable Gain range			-57	0	+6	dB
Programmable Gain step size		Monotonic		1		dB
Mute attenuation		1KHz, full scale signal		78		dB

Test Conditions

DCVDD = 1.8V, AVDD = HPVDD = 3.3V, TA = +25°C, 1kHz signal, fs = 48kHz, 24-bit audio data unless otherwise stated.

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Headphone Output (OUT1L, OUT1R, OUT2L, OUT2R)						
0dB full scale output voltage				HPVDD/3.3		Vrms
Signal to Noise Ratio	SNR	A-weighted	87	96		dB
Total Harmonic Distortion (Note 3)	THD+N	R _L = 16Ω, Po=20mW HPVDD=3.3V	-65	-72		dB
		R _L = 32Ω, Po=20mW HPVDD=3.3V		-71		dB
OUT3/OUT4 outputs (with 10kΩ / 50pF load)						
Full-scale output				HPVDD/3.3		V rms
Signal to Noise Ratio (Note 1, 2)	SNR	A-weighted	90	97		dB
Total Harmonic Distortion (Note 3)	THD	R _L = 10kΩ full-scale signal	-77	-83		dB
Channel Separation (Note 4)		5KHz signal		80		dB
Microphone Bias						
Bias Voltage	V _{MICBIAS}	MBVSEL=0		0.9*AVDD		V
		MBVSEL=1		0.75*AVDD		V
Bias Current Source	I _{MICBIAS}			3		mA
Output Noise Voltage	V _n	1kHz to 20kHz		24		nV/√Hz
Digital Input / Output						
Input HIGH Level	V _{IH}		0.7×DBVDD			V
Input LOW Level	V _{IL}			0.3×DBVDD		V
Output HIGH Level	V _{OH}	I _{OL} =1mA	0.9×DBVDD			V
Output LOW Level	V _{OL}	I _{OH} -1mA			0.1×DBVDD	V
Frequency Locked Loop (FLL)						
Reference clock frequency	F _{REF}		0.032		22	MHz
Jack Detect						
Detection switch threshold	V _{IH}		0.7×AVDD			V
	V _{IL}				0.3×AVDD	V
HPCOM						
Ground noise rejection	V _{IH}			40		dB
	V _{IL}			40		dB

TERMINOLOGY

1. Signal-to-noise ratio (dB) = SNR is a measure of the difference in level between the full scale output and the output with no signal applied. (No Auto-zero or Automute function is employed in achieving these results).
2. Dynamic range (dB) = DR is a measure of the difference between the highest and lowest portions of a signal. Normally a THD+N measurement at 60dB below full scale. The measured signal is then corrected by adding the 60dB to it. (E.g. THD+N @ -60dB= -32dB, DR= 92dB).
3. THD+N (dB) = THD+N is a ratio, of the rms values, of (Noise + Distortion)/Signal.
4. Channel Separation (dB) = Also known as Cross-Talk. This is a measure of the amount one channel is isolated from the other. Normally measured by sending a full scale signal down one channel and measuring the other.

7.2 DC-DC STEP UP CONVERTER ELECTRICAL CHARACTERISTICS

Test Conditions

$T_A = +25^\circ\text{C}$ unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
DC-DC2 and DC-DC5						
Input voltage range	V_{IN}	when used as converter	2.7	3.7	5.5	V
		when used as switch	1.2			
Output voltage range	V_{OUT}	by default (needs external component configuration)	V_{IN}		20 (30)	V
USB OTG output voltage	$V_{OUT,USB}$	$V_{IN} < 4.5\text{V}$; $I_{OUT} < 100\text{mA}$; $DCn_FBSRC[1:0]=11$		5.0		V
Output current	I_{OUT}	$V_{OUT}=30\text{V}$	0		25	mA
		$V_{OUT}=20\text{V}$ ($DCn_ILIM_=1$)			40 (18)	
		$V_{OUT}=5.0\text{V}$ ($DCn_ILIM_=1$)			170 (100)	
Switch resistance	R_{ON}	$V_{IN}=3.3\text{V}$; $V_{OUT}=3.2\text{V}$; $+25^\circ\text{C}$		0.26		Ω
		$V_{IN}=1.8\text{V}$; $V_{OUT}=1.7\text{V}$; $+25^\circ\text{C}$		0.41		
		$V_{IN}=1.2\text{V}$; $V_{OUT}=1.1\text{V}$; $+25^\circ\text{C}$		0.84		
Maximum switch current	$I_{SW,MAX}$				700	mA
Switching frequency	f_{CLK}			1.0		MHz
Maximum duty cycle	D_{MAX}	$V_{IN}=3\text{V}$; $f_{CLK}=1.0\text{MHz}$		90		%
Efficiency	H	$V_{IN}=3.8\text{V}$; $V_{OUT}=20\text{V}$; $I_{OUT}=20\text{mA}$		75		% uA
		$V_{IN}=3.8\text{V}$; $V_{OUT}=5.0\text{V}$; $I_{OUT}=100\text{mA}$		88		
Quiescent current	I_{DD}	Shutdown or switch configuration		0.1		uA
		active; no switching		260		
		active; pulse skipping		260		
Regulated feedback voltage	V_{FB}	$DCn_FBSRC[1:0]=00$		0.5		V
	V_{CURR}	$DCn_FBSRC[1:0]=01$ or 10		0.5		
Undervoltage detect	$V_{FB,UV}$	below feedback voltage		12		%
	$V_{USB,UV}$	$DCn_FBSRC[1:0]=11$		4.6		
Overvoltage detect	$V_{FB,OV}$	above feedback voltage		8		%
	$V_{USB,OV}$	$DCn_FBSRC[1:0]=11$		5.4		
Peak inductor current limit	I_{PK}	$V_{IN}=3\text{V}$; $V_{OUT}=90\%$;		700		mA
		$DCn_ILIM_=1$		450		
On resistance of NGATE driver	R_{NGATE}	P-Channel FET ($I_{PFET}=100\text{mA}$)		4.6		Ω
		N-Channel FET ($I_{NFET}=100\text{mA}$)		4.9		
Input capacitor	C_{IN}	X5R/X7R dielectric	1.0	2.2		μF
Inductor	L_F		-30%	10	+30%	μH
Inductor current rating	$I_{SAT,Lf}$		500			mA
		$DCn_ILIM_=1$	320			
Output capacitor	C_{OUT}	$DCn_FBSRC[1:0]=00$ or 11 ; $V_{OUT}=5\text{V}$	3.7	10	22	μF
		$DCn_FBSRC[1:0]=00$; $V_{OUT}=10\text{V}$	0.84	2.2	4.7	
		$DCn_FBSRC[1:0]=00$; $V_{OUT}=20\text{V}$	0.18	0.47	1.0	
		$DCn_FBSRC[1:0]=01$ or 10 ; $V_{OUT}=10\text{V}$	2.0	4.7	10	
		$DCn_FBSRC[1:0]=01$ or 10 ; $V_{OUT}=15\text{V}$	1.5	2.2	10	
		$DCn_FBSRC[1:0]=01$ or 10 ; $V_{OUT}=20\text{V}$	0.9	1.5	4.7	

7.3 DC-DC STEP DOWN CONVERTER ELECTRICAL CHARACTERISTICS

Test Conditions

$V_{IN} = 3.7V$, $V_{OUT} = 1.8V$, $T_A = +25^\circ C$ unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS			MIN	TYP	MAX	UNITS
DC-DC1 and DC-DC6								
Input Voltage	V_{IN}				2.7	3.7	5.5	V
Output Voltage	V_{OUT}				0.85		3.4	V
V _{OUT} Accuracy	V _{OUT}	V _{IN} = 3.7V V _{OUT} = 0.85V / 1.8V / 3.4V	I _{OUT} = 0.5A	Active		+/- 3.0		%
			I _{OUT} = 0.005A	Sleep		-1.5 +4.5		
Line Regulation	V _{OUT LINE}	V _{IN} = 2.7V to 5.5V V _{OUT} = 1.8V	I _{OUT} = 0.5A	Active		+/- 0.5		%
			I _{OUT} = 0.1A	Standby		+/- 0.25		
			I _{OUT} = 0.005A	Sleep		+/- 0.4	+/- 0.5	
Load Regulation	V _{OUT LOAD}	I _{OUT} = 0.001A to 1A I _{OUT} = 0A to 0.1A I _{OUT} = 0A to 0.01A	I _{OUT} = 0.5A	Active		+/- 0.2		%
			I _{OUT} = 0A to 0.1A	Standby		+/- 0.2		
			I _{OUT} = 0A to 0.01A	Sleep		+/- 0.3	+/- 0.5	
Quiescent Current	I _{Q ACTIVE}	Active (excluding switching losses)			265			µA
	I _{Q STANDBY}	Standby (excluding switching losses)			115			
	I _{QSLEEP}	Sleep			25			
Shutdown current	I _{SD}				0.01			µA
P-channel On Resistance	R _{DSP}	V _{IN} = 3.7V, I _{L(n)} = 100mA			0.09			Ω
N-channel On Resistance	R _{DSN}	V _{IN} = 3.7V, I _{L(n)} = 100mA			0.167			Ω
P-channel leakage current	I _{LXP}	V _{IN} = 3.7V, L(n) = GND			0.01			µA
N-channel leakage current	I _{LXN}	V _{IN} = 3.7V, L(n) = 3.7V			2.8			µA
Switching Frequency	f _{sw}				2.0			MHz

WM8350

Production Data

Test Conditions

$V_{IN} = 3.7$, $V_{OUT} = 1.8V$, $T_A = +25^\circ C$ unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS			MIN	TYP	MAX	UNITS
DC-DC3 and DC-DC4								
Input Voltage	V_{IN}				2.7	3.7	5.5	V
Output Voltage	V_{OUT}				0.85		3.4	V
VOUT Accuracy	V_{OUT}	$V_{IN} = 3.7V$ $V_{OUT} = 0.85V / 1.8V$ / 3.4V	$I_{OUT} = 0.5A$	Active		+/- 3.0		%
			$I_{OUT} = 0.005A$	Sleep		-1.5 +4.5		
Line Regulation	$V_{OUT\ LINE}$	$V_{IN} = 2.7V$ to 5.5V $V_{OUT} = 1.8V$	$I_{OUT} = 0.25A$	Active		+/- 0.4		%
			$I_{OUT} = 0.025A$ (100mA lim)	Standby		+/- 0.18		
			$I_{OUT} = 0.005A$	Sleep		+/- 0.4	+/- 0.5	
Load Regulation	$V_{OUT\ LOAD}$	$I_{OUT} = 1mA$ to 500mA $I_{OUT} = 0A$ to 0.05A $I_{OUT} = 0A$ to 0.010A	$I_{OUT} = 0.25A$	Active		+/- 0.5		%
			$I_{OUT} = 0.025A$	Standby		+/- 0.2		
			$I_{OUT} = 0.005A$	Sleep		+/- 0.3	+/- 0.5	
Quiescent Current	$I_Q\ ACTIVE$	Active (excluding switching losses)			318			μA
	$I_Q\ STANDBY$	Standby (excluding switching losses)			120			
	$I_Q\ SLEEP$	Sleep			25			
Shutdown current	I_{SD}				0.01			μA
P-channel On Resistance	R_{DSP}	$V_{IN} = 3.7V$, $I_{L(n)} = 100mA$			0.29			Ω
N-channel On Resistance	R_{DSN}	$V_{IN} = 3.7V$, $I_{L(n)} = 100mA$			0.2			Ω
P-channel leakage current	I_{LXP}	$V_{IN} = 3.7V$, $L(n) = GND$			0.02			μA
N-channel leakage current	I_{LXN}	$V_{IN} = 3.7V$, $L(n) = 3.7V$			1.4			μA
Switching Frequency	f_{SW}				2.0			MHz

7.4 LDO REGULATOR ELECTRICAL CHARACTERISTICS

Test Conditions

$V_{IN} = 3.7$, $V_{OUT} = 1.8V$, $T_A = +25^\circ C$ unless otherwise noted.

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
LDO1 to LDO4 (WM8350 in ACTIVE State)						
Input Voltage	V_{IN}	After start-up	1.6	3.7	5.5	V
Output voltage	V_{OUTn}		0.9		3.3	V
Regulation Accuracy				+/-3.3		%
Dropout Voltage		100mA, $V_{IN} < 1.8V$		200		mV
		100mA, $V_{IN} < 2.7V$		700		
Load current				100	150	mA
Quiescent Current			27		1% of load	μA
Leakage Current				<2.5		μA
Power Supply Rejection Ratio	PSRR	1kHz, $V_{OUT} = 1.8V$, 25mA load		-50		dB
		100Hz				
ON Resistance in switch mode	R_{ON}	$LDO_{ON_SWI} = 1$		2	3.5	Ω
LDO1 (WM8350 in OFF State)						
Output Voltage	V_{OUT1}			$0.95 \times V_{OUT1}$ in ACTIVE		V

7.5 BATTERY CHARGER

Test Conditions

$T_A = +25^\circ\text{C}$ unless otherwise noted.

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
General						
Wall adaptor voltage	LINE	When charging from wall adaptor	4.0		5.5	V
USB voltage	USB	When charging from USB power rail	4.0		5.5	V
Target voltage		CHG_VSEL=00	4.0	4.05	4.1	V
		CHG_VSEL=01	4.05	4.1	4.15	
		CHG_VSEL=10	4.1	4.15	4.2	
		CHG_VSEL=11	4.15	4.2	4.25	
Defective battery threshold				2.85		V
End of Charge Current	EOC	Programmable in register R168 CHG_EOC_SEL bits		20 to 90		mA
Trickle Charging						
Trickle charge initiation threshold (WM8350 starts trickle charging when battery is below this threshold)				CHG_VSEL - 100mV		V
50mA trickle charge current		CHG_TRICKLE_SEL = 0 (default)		36.6		mA
100mA trickle charge current		CHG_TRICKLE_SEL = 1		79.5		mA
Fast Charging						
Fast charge threshold (WM8350 can only fast-charge if battery is above this threshold)				3.1		V
Maximum fast-charge current	I_{MAX}			750		mA
Backup Battery (VRTC)						
Backup battery charger output. (Note that this backup charger voltage also determines the UVLO threshold.)			2.5	2.7	2.9	V

7.6 CURRENT LIMIT SWITCH

Test Conditions

$T_A = +25^\circ\text{C}$ unless otherwise noted.

PARAMETER	CONDITION	MIN	TYP	MAX	UNITS
Maximum input voltage		2.7		LINE	V
On resistance (at 3.3V)			2.0		Ω
Current limit flag threshold			180		mA
Current limit			215		mA
Quiescent current (EN but not ON)			7		μA
Quiescent current (EN and ON)					μA

7.7 LED DRIVERS

Test Conditions

$T_A = +25^\circ\text{C}$ unless otherwise noted.

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
ISINKA, ISINKB						
Sink Current		duty cycle = 20%			200	mA
		continuous			40	
ISINKC, ISINKD, ISINKE						
Sink Current					20	mA
Output voltage drop		10mA load		0.8		V

7.8 GENERAL PURPOSE INPUTS / OUTPUTS (GPIO)

Test Conditions

$T_A = +25^\circ\text{C}$ unless otherwise noted.

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
GPIO0 to GPIO3						
Input HIGH Level	V_{IH}		0.7×VRTC			V
Input LOW Level	V_{IL}				0.3×VRTC	V
Output HIGH Level	V_{OH}	sinking 2 mA	0.9×VRTC			V
Output LOW Level	V_{OL}	sourcing 2 mA			0.1×VRTC	V
Sink / source current						mA
Pull-up resistance to VRTC	R_{PU}	GPn_PU = 1	310			kΩ
Pull-down resistance	R_{PD}	GPn_PD = 1	225			kΩ
GPIO4 to GPIO9						
Logic levels			See Section 7.9			
Sink / source current						mA
Pull-up resistance to DBVDD	R_{PU}	GPn_PU= 1	220			kΩ
Pull-down resistance	R_{PD}	GPn_PD = 1	144			kΩ
GPIO10 to GPIO12						
Input HIGH Level	V_{IH}		2.0			V
Input LOW Level	V_{IL}				0.9	V
Output HIGH Level	V_{OH}	sinking 2 mA	0.9× LINE			V
Output LOW Level	V_{OL}	sourcing 2 mA			0.1× GPIO_VD D	V
Sink / source current						mA
Pull-up resistance to LINE	R_{PU}	GPn_PU = 1	250			kΩ
Pull-down resistance	R_{PD}	GPn_PD = 1	135			kΩ

7.9 DIGITAL INTERFACES

Test Conditions

$T_A = +25^\circ\text{C}$ unless otherwise noted.

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SDA, SCLK, MCLK, BCLK, LRCLK, ADCDATA, DACDATA, GPIO4 to GPIO9						
Input HIGH Level	V_{IH}		$0.7 \times DBVDD$			V
Input LOW Level	V_{IL}				$0.3 \times DBVDD$	V
Output HIGH Level	V_{OH}	sinking 1mA	$0.9 \times DBVDD$			V
Output LOW Level	V_{OL}	sourcing 1mA			$0.1 \times DBVDD$	V

7.10 AUXILIARY ADC

Test Conditions

$T_A = +25^\circ\text{C}$ unless otherwise noted.

PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNITS
Input resistance (AUX1,2,3,4, USB, LINE, BATT and CHIPTEMP)	AUXADC_SCALEn [1:0] = 00		∞	∞	∞	Ω
	AUXADC_SCALEn [1:0] = 01			2.2		$k\Omega$
	AUXADC_SCALEn [1:0] = 10		330		660	$k\Omega$
	AUXADC_SCALEn [1:0] = 11		330		440	$k\Omega$
Input Voltage range. AUX1,2,3,4,USB,LINE,BATT and CHIPTEMP ($V_{RTC} = 2.7\text{V}$ & V_{LINE} (max)= 5.5V, $V_{BG}=1.25\text{V}$)	AUXADC_SCALEn [1:0] = 01 AUXADC_REF = 0				V_{BG}	V
	AUXADC_SCALEn [1:0] = 01 AUXADC_REF = 1				V_{RTC}	V
	AUXADC_SCALEn [1:0] = 10 AUXADC_REF = 0				$2 \times V_{BG}$	V
	AUXADC_SCALEn [1:0] = 10 AUXADC_REF = 1				$2 \times V_{RTC}$	V
	AUXADC_SCALEn [1:0] = 11 AUXADC_REF = 0				V_{LINE}	V
	AUXADC_SCALEn [1:0] = 11 AUXADC_REF = 1				$4 \times V_{BG}$	V
	Input capacitance (AUX1,2,3,4, USB, LINE, BATT and CHIPTEMP)	Input is selected (INPUT_SELECT) and AUXADC_SCALEn [1:0] not = 00		2.08		pF
VRTC quiescent current	AUX_RBMODE = 0, AUXADC_ENA = 1			140		μA
VRTC quiescent current	AUX_RBMODE = 1 AUXADC_ENA = 1			151		μA
LINE_INT quiescent current					<<1	mA
ADCCLK frequency		f_{AUXCLK}	400	470/512	800	kHz
ADC Resolution				12		bits
ADC Conversion Time				13		CLK periods
Aux ADC accuracy	Non-calibrated (calibration possible using the VBG input on AUX3). 1% of this variation due to BG variation over temperature.			2.2		%

8 TYPICAL POWER CONSUMPTION

ADC Master Mode

48kHz

AVDD (V)	HPVDD (V)	DBVDD (V)	DCVDD (V)	IAVDD (mA)	IHPVDD (mA)	IDB (mA)	IDC (mA)	Power Consumption (mW)
2.5	2.5	1.71	1.71	3.6	0.000014	0.55	2.3	13.87
3.3	3.3	3.3	1.8	4.46	0.00003	1.085	2.4	22.62
3.6	3.6	3.6	3.6	4.79	0.000028	1.18	5.67	41.90

ADC Master Mode

1kHz Tone 100mVpk-pk

AVDD (V)	HPVDD (V)	DBVDD (V)	DCVDD (V)	IAVDD (mA)	IHPVDD (mA)	IDB (mA)	IDC (mA)	Power Consumption (mW)
2.5	2.5	1.71	1.71	3.6	0.00009	0.5	2.14	13.51
3.3	3.3	3.3	1.8	4.4	0.00016	1.02	2.3	22.03
3.6	5.5	3.6	3.6	4.8	0.00008	1.12	5.3	40.39

ADC Master Mode

Pink Noise

AVDD (V)	HPVDD (V)	DBVDD (V)	DCVDD (V)	IAVDD (mA)	IHPVDD (mA)	IDB (mA)	IDC (mA)	Power Consumption (mW)
2.5	2.5	1.71	1.71	3.58	0.000004	0.51	2.1	13.41
3.3	3.3	3.3	1.8	4.43	0.00026	1	2.2	21.88
3.6	5.5	3.6	3.6	4.8	0.000085	1.1	5.2	39.96

ADC Slave Mode

44.1kHz

AVDD (V)	HPVDD (V)	DBVDD (V)	DCVDD (V)	IAVDD (mA)	IHPVDD (mA)	IDB (mA)	IDC (mA)	Power Consumption (mW)
2.5	2.5	1.71	1.71	3.4	0.00002	0.02	2.2	12.30
3.3	3.3	3.3	1.8	4.2	0.00041	0.05	2.3	18.17
3.6	3.6	3.6	3.6	4.4	0.0004	0.05	5.33	35.21

DAC OUT1 Master Mode

44.1kHz, 10kΩ Load

AVDD (V)	HPVDD (V)	DBVDD (V)	DCVDD (V)	IAVDD (mA)	IHPVDD (mA)	IDB (mA)	IDC (mA)	Power Consumption (mW)
2.5	2.5	1.71	1.71	2.97	0.299	0.193	1.69	11.39
3.3	3.3	3.3	1.8	4.14	0.432	0.39	1.78	19.58
3.6	3.6	3.6	3.6	4.54	0.486	0.461	4.28	35.16

48kHz, 10kΩ Load

AVDD (V)	HPVDD (V)	DBVDD (V)	DCVDD (V)	IAVDD (mA)	IHPVDD (mA)	IDB (mA)	IDC (mA)	Power Consumption (mW)
2.5	2.5	1.71	1.71	2.82	0.3	0.2	2	11.56
3.3	3.3	3.3	1.8	3.94	0.45	0.42	2.12	19.69
3.6	3.6	3.6	3.6	4.33	0.51	0.46	4.9	36.72